 TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT (Under 37 CFR 1.97(b) or 1.97(c))				Docket No. 050685-US	
Re Application Of: Koenenkamp					
Application No.	Filing Date	Examiner	Customer No.	Group Art Unit	Confirmation No.
10/532,190	21 April 2005		30234		
Title: Field Effect Transistor and Method of Its Fabrication					
<p style="text-align: center;">Address to: Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450</p> <p style="text-align: center;">37 CFR 1.97(b)</p> <p>1. <input checked="" type="checkbox"/> The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114.</p> <p style="text-align: center;">37 CFR 1.97(c)</p> <p>2. <input type="checkbox"/> The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:</p> <p style="padding-left: 40px;"><input type="checkbox"/> the statement specified in 37 CFR 1.97(e);</p> <p style="text-align: center;">OR</p> <p style="padding-left: 40px;"><input type="checkbox"/> the fee set forth in 37 CFR 1.17(p).</p>					

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT

JUN 29 2005

(Under 37 CFR 1.97(b) or 1.97(c))

Docket No.

050685-US

In Re Application

Koenenkamp

Application No. 10/532,190	Filing Date 21 April 2005	Examiner	Customer No. 30234	Group Art Unit	Confirmation No.
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Title: Field Effect Transistor and Method of Its Fabrication

Payment of Fee

(Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p))

- ☐ A check in the amount of _____ is attached.
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Signature of Person Mailing Correspondence

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Signature

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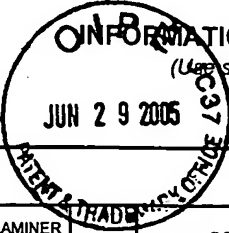
Dated: 27 June 2005

Karl Hormann

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CC:

				ATTY DOCKET NO. 050685-US		APPLICATION NO. 10/532,190		
				APPLICANT(S) Koenenkamp				
				FILING DATE 21 April 2005		GROUP ART UNIT		
U.S. PATENT DOCUMENTS								
*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
	A	6,515,325 B1	2/2003	Farnworth et al.	257	530		
U.S. PATENT APPLICATION PUBLICATIONS								
*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
	AA	2002/0001905 A1	1/3/2002	Choi et al.	438	268		
	BB	2003/0132461 A1	7/17/2003	Roesner et al.	257	233		
FOREIGN PATENT DOCUMENTS								
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
	a	100 36 897 C1	1/2002	Germany	H01L	29/775	YES	NO
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)								
		aa	Engelhardt R. et al.: Growth of Compound Semiconductors in Nanometer Sized Channels of Polymers; Mat.Res.Soc.Symp.Proc. Vol. 672 (2201) pp 08.8.1 - 08.8.6					
EXAMINER				DATE CONSIDERED				

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.